Texas Instruments, Inc. High Speed Interface Products

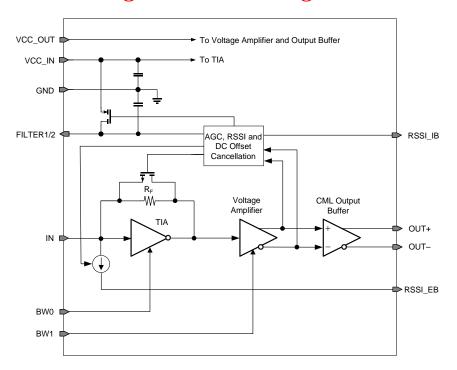
ONET8551T APD Bonding

Alex Davidson



ONET8551T

11.3Gb/s High Gain Limiting TIA with RSSI



Applications

- 10 Gigabit Ethernet Optical Receivers
- 8x and 10x Fibre Channel Optical Receivers
- SONET OC-192 Optical Receivers
- 10G PON
- 6G & 10G CPRI and OBSAI
- PIN and APD Preamplifiers

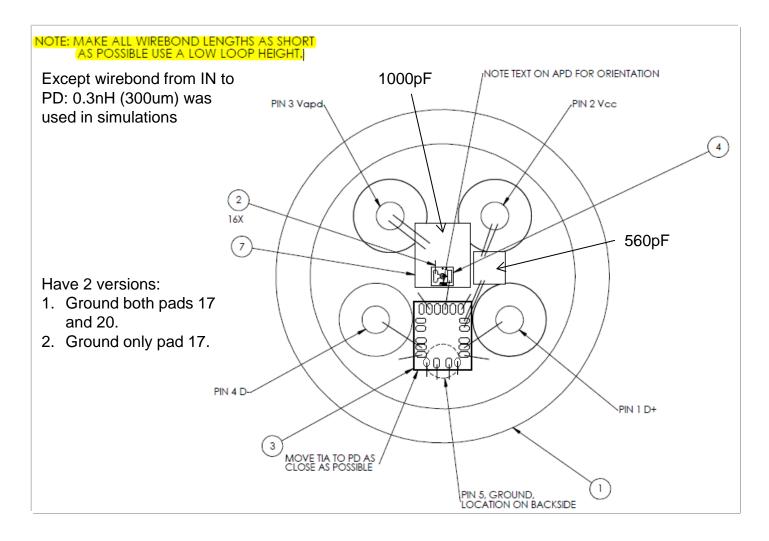
Features

- 9GHz Bandwidth
- 10kΩ Differential Transimpedance
- 0.9μA_{RMS} Input Referred noise
- -20dBm Sensitivity
- 2.5mApp Input Overload Current
- Received Signal Strength Indicator
- 92mW Typical Power Dissipation
- Single +3.3V Supply
- -40°C to 100°C Ambient Operation
- On Chip Supply Filter Capacitor
- Die size: 870µm x 1036µm

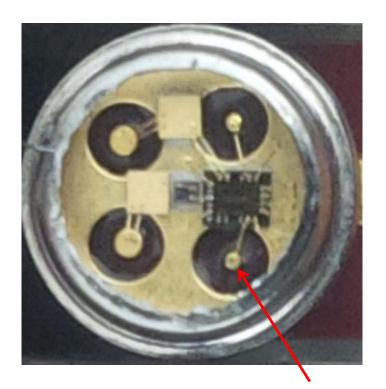
Benefits

- One TIA for PIN and APD applications
- High Gain for reduced crosstalk
- Low Bandwidth and Transimpedance Variation over Temperature
- Low Power
- Bandwidth adjustment

ONET8551T *APD Bonding Recommendations*



ONET8551T *APD Bonding Example*



Use a header with 50Ω pins